

Description

The AON1605 uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 2.5V. This device is suitable for use as a Battery protection or in other Switching application.

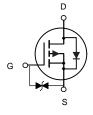


DFN1006-3L

General Features

 $V_{DS} = -20V I_{D} = -0.8A$

$$\begin{split} &R_{DS(ON)} < 560 \text{ } m\Omega \text{@ } V_{GS}\text{=-}4.5V \\ &R_{DS(ON)} < 780 \text{ } m\Omega \text{@ } V_{GS}\text{=-}2.5V \\ &ESD \text{ } Rating: 1500V \text{ } HBM \end{split}$$



P-Channel MOSFET

Application

Battery protection

Load switch

Uninterruptible power supply

Package Marking and Ordering Information

Product ID	Pack	Brand	Qty(PCS)
AON1605	DFN1006-3L	HXY MOSFET	10000

Absolute Maximum Ratings (T_A=25 ℃ unless otherwise noted)

Symbol	Parameter	Limit	Unit
V _D s	Drain-Source Voltage	-20	V
Vgs	Gate-Source Voltage	±12	V
I _D	Drain Current-Continuous	-0.8	A
P _D	Maximum Power Dissipation	100	mW
T _J ,T _{STG}	Operating Junction and Storage Temperature Range	-55 To 150	°C
RөJA	Thermal Resistance,Junction-to-Ambient (Note 2)	1250	°C/W

$T_a=25$ °C unless otherwise noted

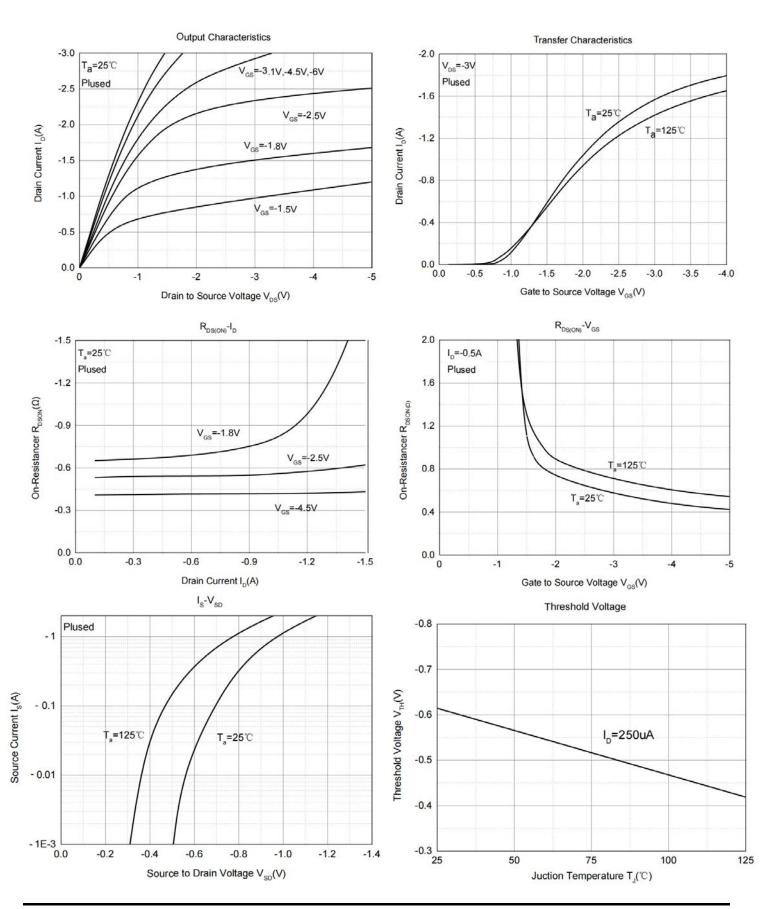
Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
STATIC PARAMETERS						
Drain-source breakdown voltage	V(BR)DSS	V _G S = 0V, I _D =-250µA	-20			V
Zero gate voltage drain current	Inss	V _{DS} =-20V,V _{GS} = 0V			-1	μA
Gate-body leakage current	Igss	V _{GS} =±10V, V _{DS} = 0V			±20	uA
Gate threshold voltage (note 2)	VGS(th)	V _{DS} =V _{GS} , I _D =-250µA	-0.35	-0.61	-1.1	V
		V _{GS} =-4.5V, I _D =-1A		350	390	mΩ
Drain-source on-resistance(note 2)	RDS(on)	V _{GS} =-2.5V, I _D =-0.8A		395	460	mΩ
		V _{GS} =-1.8V, I _D =-0.5A		450		mΩ
Forward tranconductance(note 2)	grs	V _{DS} =-10V, I _D =-0.54A		1.2		S
Diode forward voltage	V _{SD}	I _S =-0.5A, V _{GS} = 0V			-1.2	V
DYNAMIC PARAMETERS(note 4)						
Input Capacitance	C _{iss}			113		pF
Output Capacitance	Coss	V _{DS} =-16V,V _{GS} =0V,f =1MHz		15		pF
Reverse Transfer Capacitance	C _{rss}			9		pF
SWITCHING PARAMETERS (note 4)						
Turn-on delay time (note 3)	td(on)			9		ns
Turn-on rise time (note 3)	tr	V _{DD} =-4.5V,V _{GS} =-10V,		5.7		ns
Turn-off delay time (note 3)	t _{d(off)}	I_D =-200mA, R_{GEN} =10 Ω		32.6		ns
Turn-off fall time (note 3)	t f			20.3		ns

Notes:

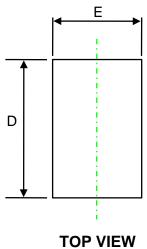
- 1. Surface mounted on FR4 board using the minimum recommended pad size.
- 2. Pulse Test: Pulse Width=300µs, Duty Cycle=2%.
- 3. Switching characteristics are independent of operating junction temperatures.
- 4. Guaranteed by design, not subject to producting.

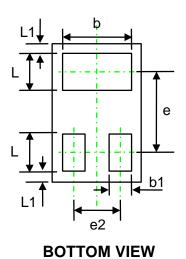


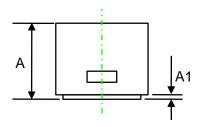
Typical Electrical



DFN1006-3L Package Outline Dimensions







SIDE VIEW

Symbol	Dimensions In Millimeters (mm)			
	Min.	Тур.	Max.	
Α	0.44	0.47	0.50	
A1	0.00	0.03	0.05	
D	0.95	1.00	1.05	
Е	0.55	0.60	0.65	
b	0.45	0.50	0.55	
е	-	0.65	-	
e2	-	0.35	-	
L1		0.05 REF.		
L	0.20	0.25	0.30	
b1	0.10	0.15	0.20	



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